

Description

The SX30N15HD uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 10V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 150V$ $I_D = 30A$

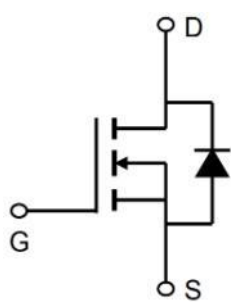
$R_{DS(ON)} < 78m\Omega @ V_{GS}=10V$

Application

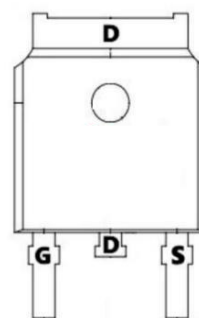
Automotive lighting

Load switch

Uninterruptible power supply



TO-252-3L



Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	150	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D @ T_C=25^\circ C$	Drain Current, $V_{GS} @ 10V$	30	A
$I_D @ T_C=100^\circ C$	Drain Current, $V_{GS} @ 10V$	21	A
IDM	Pulsed Drain Current ¹	90	A
$P_D @ T_C=25^\circ C$	Total Power Dissipation	60	W
TSTG	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$
$R_{\theta JA}$	Maximum Thermal Resistance, Junction ambient	62.5	$^\circ C/W$
$R_{\theta JC}$	Maximum Thermal Resistance, Junction-case	2.5	$^\circ C/W$

Electrical Characteristics@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	150	175	-	V
IGSS	Gate-body Leakage current	V _{DS} = 0V, V _{GS} = ±20V	-	-	±100	nA
IDSS	Zero Gate Voltage Drain Current T _J = 25°C	V _{DS} = 150V, V _{GS} = 0V	-	-	1	μA
IDSS	Zero Gate Voltage Drain Current T _J = 100°C		-	-	100	μA
VGS(th)	Gate-Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	2.0	3.0	4.5	V
RDS(on)	Drain-Source On-Resistance ²	V _{GS} = 10V, I _D = 10A	-	63	78	mΩ
RDS(on)	Drain-Source On-Resistance ²	V _{GS} = 4.5V, I _D = 8A	-	72	90	
gfs	Transconductance	V _{DS} = 5V, I _D = 10A	-	23	-	S
Ciss	Input Capacitance	V _{DS} = 75V, V _{GS} = 0V, f = 1MHz	-	630	-	pF
Coss	Output Capacitance		-	50	-	
Crss	Reverse Transfer Capacitance		-	13.5	-	
R _g	Gate Resistance	V _{GS} = 0V, V _{DS} Open, f = 1MHz	-	5	-	Ω
Q _g	Total Gate Charge	V _{GS} = 10V, V _{DD} = 75V, I _D = 10A	-	11	-	nC
Q _{gs}	Gate-Source Charge		-	1.2	-	
Q _{gd}	Gate-Drain Charge		-	4	-	
td(on)	Turn-On Delay Time	V _{GS} = 10V, V _{DD} = 75V, R _G = 10Ω, I _D = 10A	-	9.8	-	nS
t _r	Rise Time		-	6	-	
td(off)	Turn-Off Delay Time		-	15	-	
t _f	Fall Time		-	4.1	-	
VSD	Diode Forward Voltage ²	I _S = 10A, V _{GS} = 0V	-	-	1.2	V
t _{rr}	Body Diode Reverse Recovery Time	V _R = 75V, I _F = 10A, dI/dt= 100A/μs	-	55	-	nS
Q _{rr}	Body Diode Reverse Recovery Charge		-	124	-	nC

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is VDD=72V,VGS=10V,L=0.1mH,IAS=13A
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I D and I DM , in real applications , should be limited by total power dissipation.

Typical Characteristics

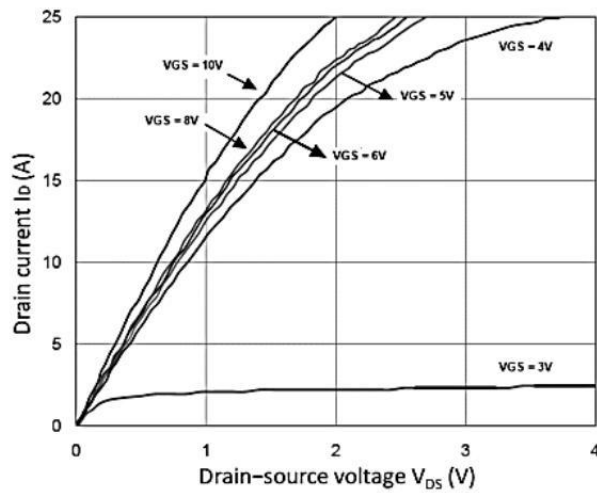


Figure 1. Output Characteristics

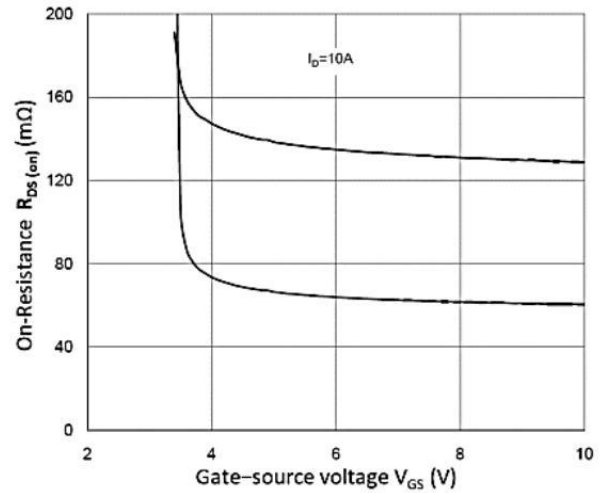


Figure 2. $R_{DS(on)}$ vs. V_{GS}

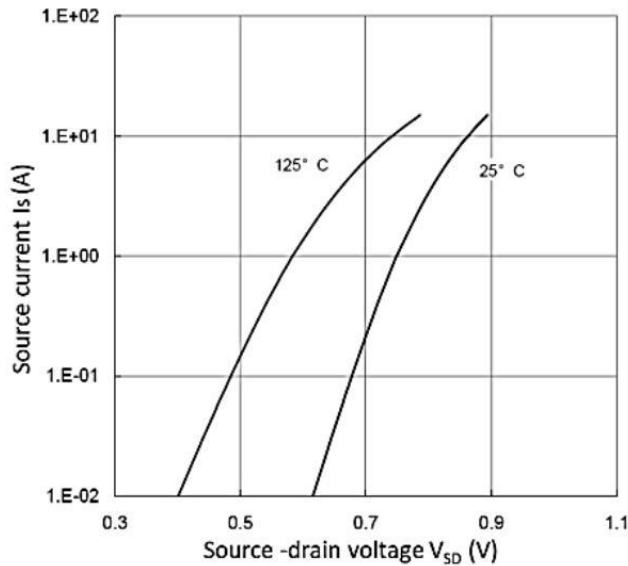


Figure 3. Forward Characteristics of Reverse

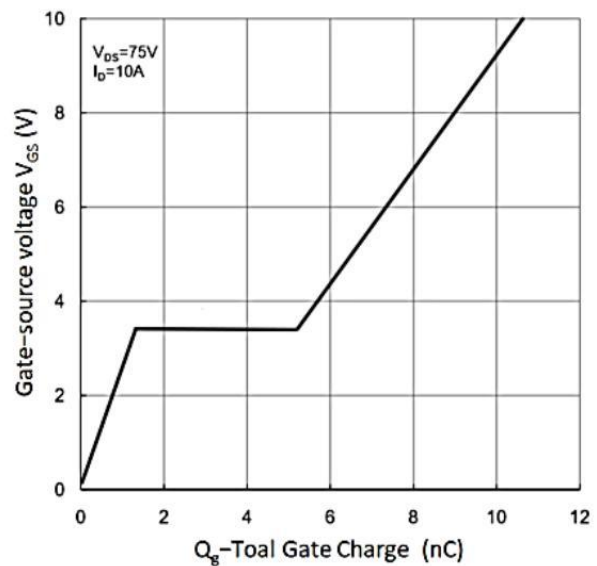


Figure 4. Gate Charge Characteristics

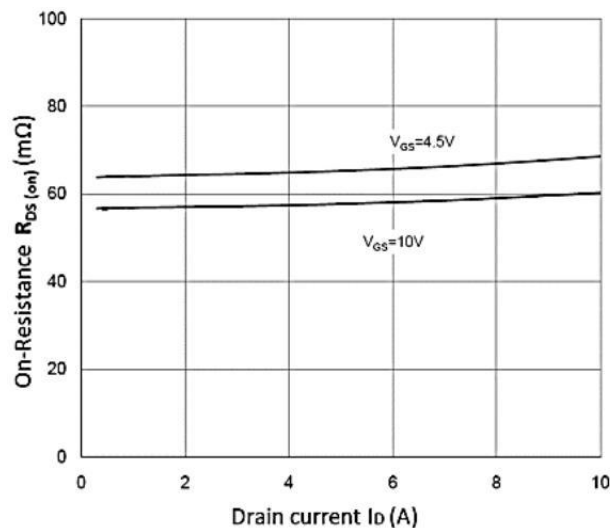


Figure 5. $R_{DS(on)}$ vs. I_D

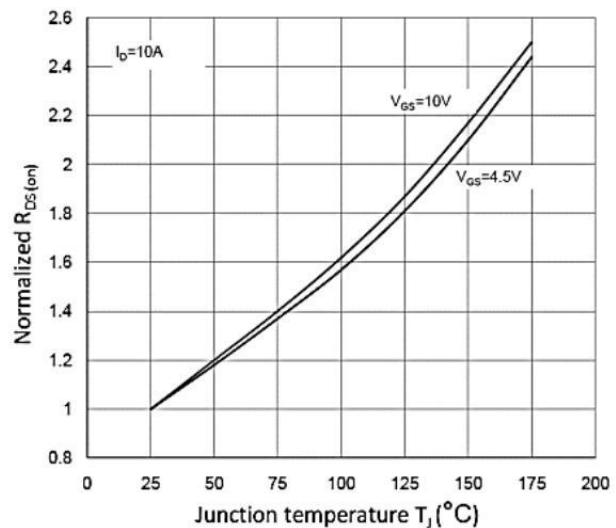


Figure 6. Normalized $R_{DS(on)}$ vs. T_J

Typical Characteristics

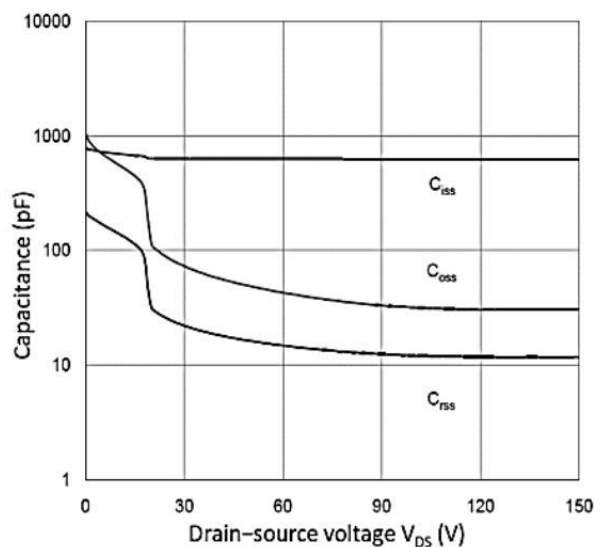


Figure 7. Capacitance Characteristics

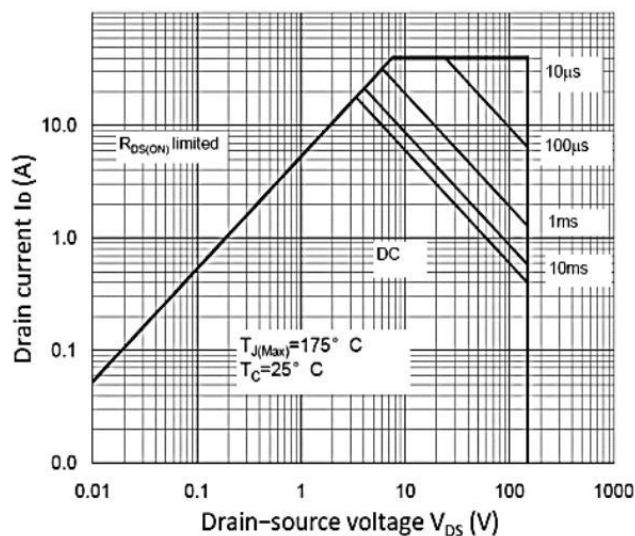


Figure 8. Safe Operating Area

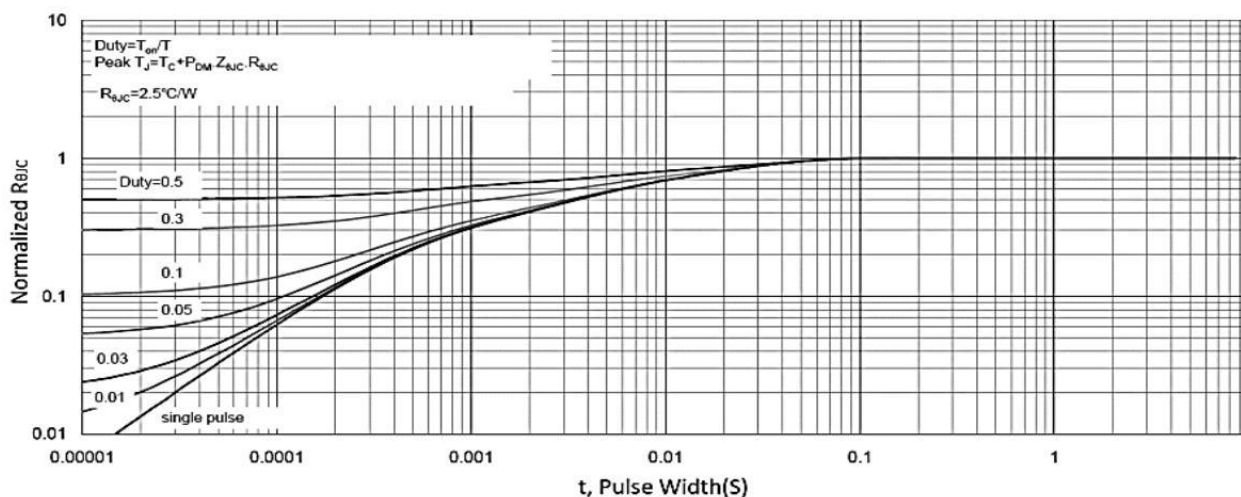


Figure 9. Normalized Maximum Transient Thermal Impedance

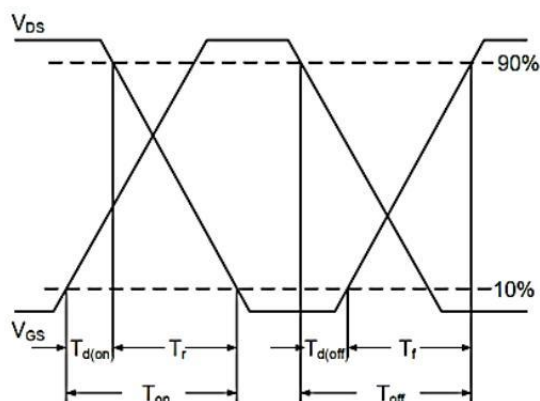


Figure 10. Switching Time Waveform

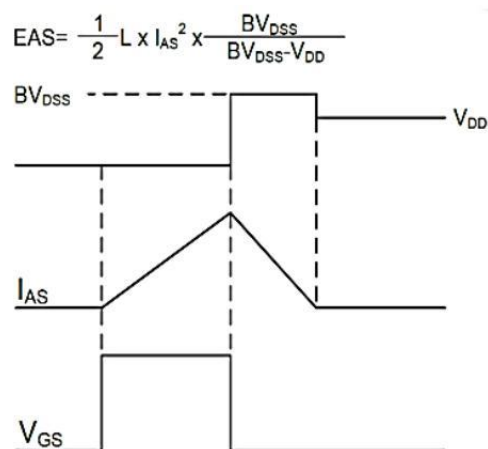
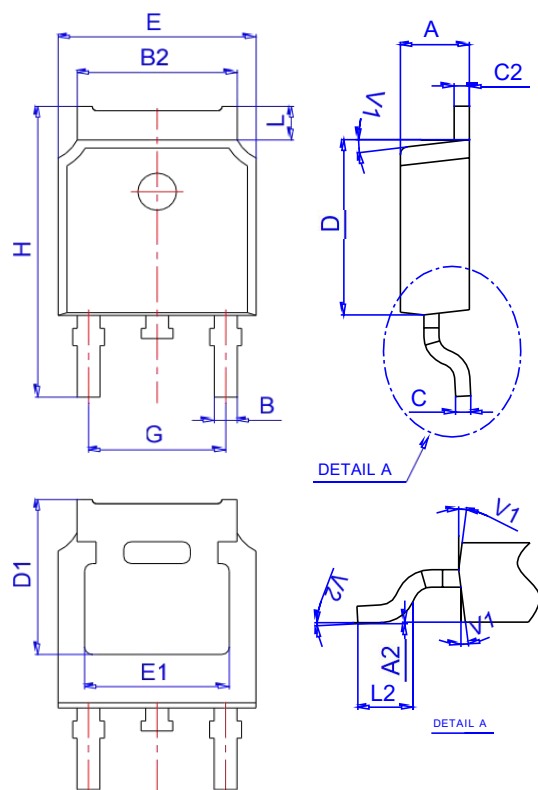


Figure 11. Unclamped Inductive Switching

$$EAS = \frac{1}{2} L \times I_{AS}^2 \times \frac{BV_{DSS}}{BV_{DSS} - V_{DD}}$$

Package Mechanical Data: TO-252-3L



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	TO-252-3L		2500